# UNISONIC TECHNOLOGIES CO., LTD

6N60-P Power MOSFET

# **6A, 600V N-CHANNEL POWER MOSFET**

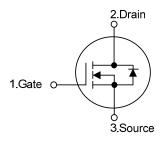
#### DESCRIPTION

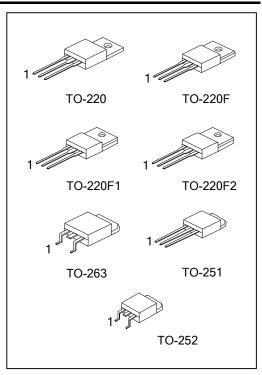
The UTC **6N60-P** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in switching power supplies and adaptors.

#### **■ FEATURES**

- \*  $R_{DS(ON)}$  < 1.75 $\Omega$  @  $V_{GS}$  = 10V,  $I_{D}$  = 3A
- \* Fast switching capability
- \* Avalanche energy tested
- \* Improved dv/dt capability, high ruggedness

#### ■ SYMBOL

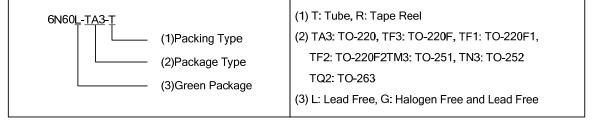




#### **■** ORDERING INFORMATION

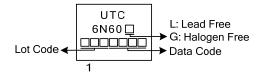
Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	Fackage	1	2	3	Facking	
6N60L-TA3-T	6N60G-TA3-T	TO-220	G	D	S	Tube	
6N60L-TF1-T	6N60G-TF1-T	TO-220F1	G	D	S	Tube	
6N60L-TF2-T	6N60G-TF2-T	TO-220F2	G	D	S	Tube	
6N60L-TF3-T	6N60G-TF3-T	TO-220F	G	D	S	Tube	
6N60L-TM3-T	6N60G-TM3-T	TO-251	G	D	S	Tube	
6N60L-TN3-R	6N60G-TN3-R	TO-252	G	D	S	Tape Reel	
6N60L-TQ2-T	6N60G-TQ2-T	TO-263	G	D	S	Tube	
6N60L-TQ2-R	6N60G-TQ2-R	TO-263	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



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#### ■ MARKING



#### ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>C</sub> = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	600	V
Gate-Source Voltage		$V_{GSS}$	±30	V
Avalanche Current (Note 2)		$I_{AR}$	6	Α
Continuous Drain Current		$I_{D}$	6	Α
Pulsed Drain Current (Note 2)		$I_{DM}$	24	Α
Avalanche Energy	Single Pulsed (Note 3)	E <sub>AS</sub>	260	mJ
	Repetitive (Note 2)	E <sub>AR</sub>	13	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	3.0	ns
Power Dissipation	TO-220/TO-263		125	W
	TO-220F/TO-220F1	В	40	W
	TO-220F2	$P_D$	42	W
	TO-251/TO-252		55	W
Junction Temperature		$T_J$	+150	°C
Operating Temperature		T <sub>OPR</sub>	-55 ~ +150	°C
Storage Temperature		$T_{STG}$	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating : Pulse width limited by  $T_{\mathsf{J}}$
- 3. L = 14mH,  $I_{AS}$  = 6A,  $V_{DD}$  = 50V,  $R_{G}$  = 25  $\Omega$ , Starting  $T_{J}$  = 25°C
- 4.  $I_{SD} \le 6A$ , di/dt  $\le 200A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_J = 25^{\circ}C$

#### **■ THERMAL DATA**

PARAMETER		SYMBOL	RATING	UNIT	
Junction to Ambient	TO-220/TO-220F2 TO-220F/TO-220F1 TO-263	$\theta_{JA}$	62.5	°C/W	
	TO-251/TO-252		110		
Junction to Case	TO-220/TO-263	θ <sub>JC</sub>	1.0		
	TO-220F/TO-220F1		3.2	°C/W	
	TO-220F2		2.97	C/VV	
	TO-251/TO-252		2.27		

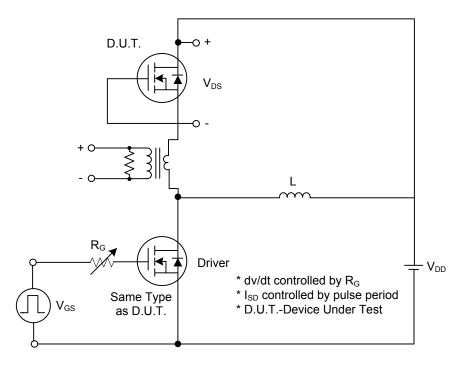
## ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub> =25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		$BV_{DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	600			V
Drain-Source Leakage Current		I <sub>DSS</sub>	$V_{DS} = 600V, V_{GS} = 0V$			10	μΑ
Gate- Source Leakage Current	Forward	1000	$V_{GS} = 30V, V_{DS} = 0V$			100	nA
	Reverse		$V_{GS} = -30V, V_{DS} = 0V$			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS}/\triangle T_{J}$	I <sub>D</sub> =250μA, Referenced to 25°C		0.53		V/°C
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance		R <sub>DS(ON)</sub>	$V_{GS} = 10V, I_D = 3A$		1.2	1.75	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance	nput Capacitance				751		pF
Output Capacitance		Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0 MHz		89		pF
Reverse Transfer Capacitance		$C_{RSS}$			17		pF
SWITCHING CHARACTERISTICS	S						
Total Gate Charge		$Q_G$	V <sub>DS</sub> =50V, I <sub>D</sub> =1.3A, V <sub>GS</sub> =10 V (Note 1, 2)		25		nC
Gate-Source Charge		$Q_GS$			4.9		nC
Gate-Drain Charge		$Q_GD$	(Note 1, 2)		9.4		nC
Turn-On Delay Time		$t_{D(ON)}$			60		ns
Turn-On Rise Time		$t_R$	$V_{DD}$ =30V, $I_{D}$ =0.5A, $R_{G}$ =25 $\Omega$		80		ns
Turn-Off Delay Time		$t_{D(OFF)}$	I <sub>G</sub> = 100μA (Note 1, 2)		230		ns
Turn-Off Fall Time		$t_{F}$			90		ns
DRAIN-SOURCE DIODE CHARA	CTERISTIC	CS AND MAXI	MUM RATINGS				
Drain-Source Diode Forward Voltage		$V_{SD}$	$V_{GS} = 0 \text{ V}, I_{S} = 6 \text{ A}$			1.4	V
Maximum Continuous Drain-Source Diode		Is				6	Α
Forward Current						O	А
Maximum Pulsed Drain-Source Diode		I <sub>SM</sub>				24	Α
Forward Current						<b>4</b>	^
Reverse Recovery Time		t <sub>rr</sub>	$V_{GS} = 0 \text{ V}, I_S = 6 \text{ A},$		290		ns
Reverse Recovery Charge		$Q_{RR}$	dI <sub>F</sub> /dt = 100 A/μs (Note 1)		3.0		μC

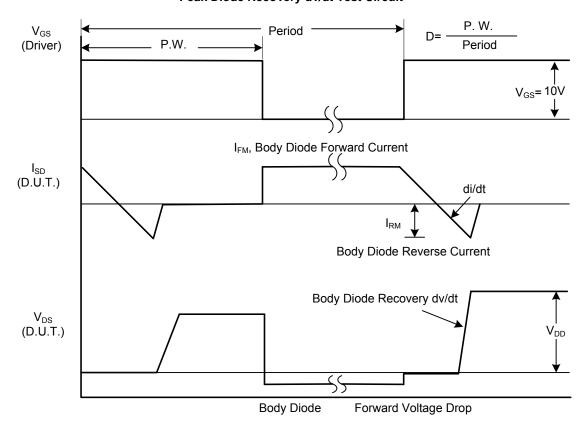
Notes: 1. Pulse Test: Pulse width  $\leq$  300 $\mu$ s, Duty cycle  $\leq$  2%.

<sup>2.</sup> Essentially independent of operating temperature.

#### **■ TEST CIRCUITS AND WAVEFORMS**

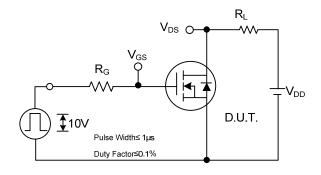


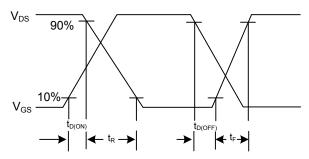
#### Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

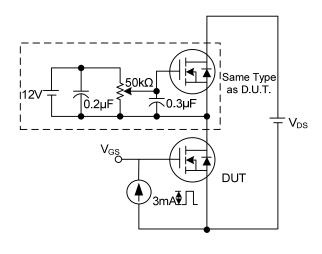
### ■ TEST CIRCUITS AND WAVEFORMS (Cont.)

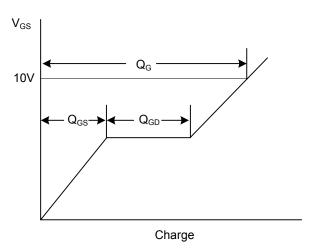




**Switching Test Circuit** 

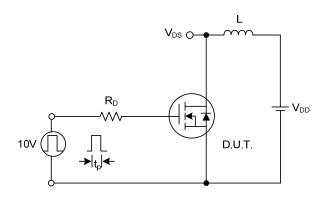
**Switching Waveforms** 

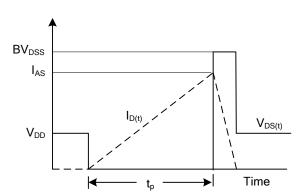




**Gate Charge Test Circuit** 

**Gate Charge Waveform** 

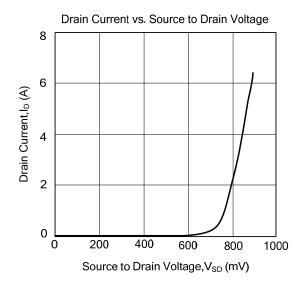


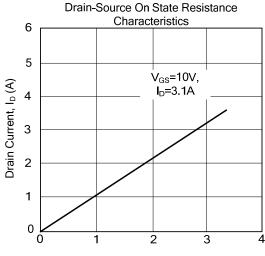


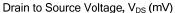
**Unclamped Inductive Switching Test Circuit** 

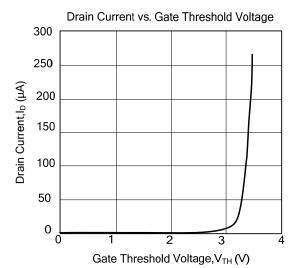
**Unclamped Inductive Switching Waveforms** 

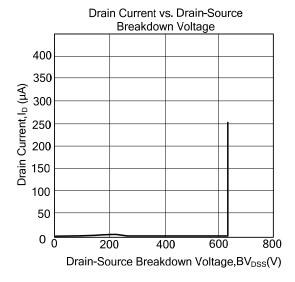
#### **■ TYPICAL CHARACTERISTICS**











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